

SILICON PROGRAMMABLE UNIJUNCTION TRANSISTORS





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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N6027 and 2N6028 devices are silicon programmable unijunction transistors, manufactured in an epoxy molded package, designed for adjustable (programmable) characteristics such as Valley Current (I_V), Peak Current (I_P), and Intrinsic Standoff Ratio (η).

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: $(T_A=25^{\circ}C)$	SYMBOL		UNITS
Gate-Cathode Forward Voltage	VGKF	40	V
Gate-Cathode Reverse Voltage	VGKR	5.0	V
Gate-Anode Reverse Voltage	VGAR	40	V
Anode-Cathode Voltage	V _{AK}	40	V
Peak Non-Repetitive Forward Current (t=10µs)	ITSM	5.0	А
Peak Repetitive Forward Current (t=20µs, D.C.=1.0%)	ITRM	2.0	А
Peak Repetitive Forward Current (t=100µs, D.C.=1.0%)	ITRM	1.0	А
DC Forward Anode Current	Ι _Τ	150	mA
DC Gate Current	۱ _G	50	mA
Power Dissipation	PD	300	mW
Operating Junction Temperature	ТЈ	-50 to +100	°C
Storage Temperature	T _{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

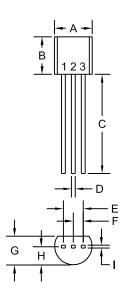
		<u>2N6</u>	<u>6027</u>	,	028	
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNITS
IGAO	V _S =40V	-	10	-	10	nA
I _{GKS}	V _S =40V	-	50	-	50	nA
۱ _Р	V _S =10V, R _G =1.0MΩ	-	2.0	-	0.15	μA
۱ _Р	V_{S} =10V, R _G =10k Ω	-	5.0	-	1.0	μA
١ _V	V _S =10V, R _G =1.0MΩ	-	50	-	25	μA
١ _V	V_{S} =10V, R _G =10k Ω	70	-	25	-	μA
١ _V	V _S =10V, R _G =200Ω	1.5	-	1.0	-	mA
VT	V _S =10V, R _G =1.0MΩ	0.2	1.6	0.2	0.6	V
VT	V_{S} =10V, R _G =10k Ω	0.2	0.6	0.2	0.6	V
V _F	I _F =50mA	-	1.5	-	1.5	V
VO	V _B =20V, C _C =0.2µF	6.0	-	6.0	-	V
t _r	V_B =20V, C _C =0.2µF	-	80	-	80	ns

R2 (4-February 2014)



Semiconductor Corp.

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TO-92 CASE - MECHANICAL OUTLINE

DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.175	0.205	4.45	5.21		
В	0.170	0.210	4.32	5.33		
С	0.500	-	12.70	-		
D	0.016	0.022	0.41	0.56		
Е	0.100		2.54			
F	0.050		1.27			
G	0.125	0.165	3.18	4.19		
Н	0.080	0.105	2.03	2.67		
	0.015		0.38			
TO-92 (REV: R1)						

LEAD CODE:

1) Anode 2) Gate

R1

3) Cathode

MARKING: FULL PART NUMBER

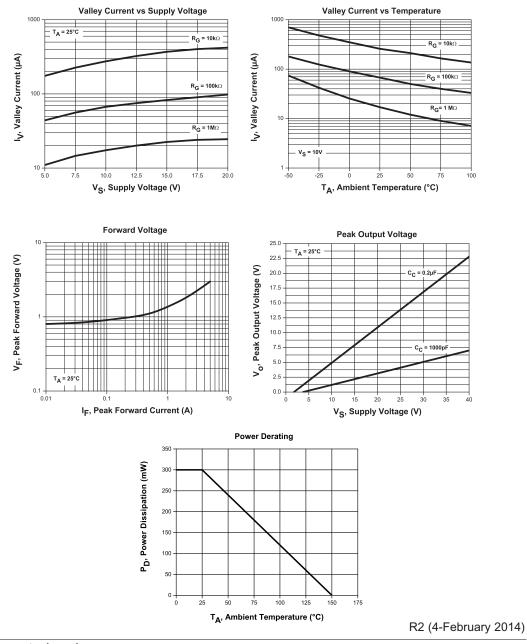
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2N6027 2N6028

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TYPICAL ELECTRICAL CHARACTERISTICS

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OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- · Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

ss your design challenges.

· Custom product packing

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits

Custom bar coding for shipments

Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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